



60V N-Channel Enhancement Mode MOSFET

Voltage 60 V Current 35 A

Features

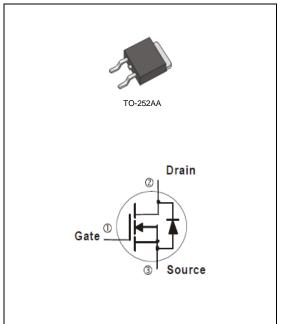
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_{D}@20A$ <21m Ω
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@12A$ < $24m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 Standard

Mechanical Data

• Case: TO-252AA Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Weight: 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	60	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	l _D	35	А	
	T _C =100°C		22		
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	140		
Power Dissipation	T _C =25°C	Po	75.0	14/	
	T _C =100°C		37.5	W	
Continuous Drain Current	T _A =25°C	I _D	4.7		
	T _A =70°C		3.8	Α	
Power Dissipation	T _A =25°C	D-	1.3	W	
Power Dissipation	T _A =70°C	Pb	0.9		
Single Pulse Avalanche Energy (Note 6)		E _{AS}	42	mJ	
Operating Junction and		T_{J} , T_{STG}	55.475	°C	
Storage Temperature Range			-55~175	10	
Typical Thermal resistance (Note 4,5)	Junction to Case	R _{θJC}	2	°C/W	
	Junction to Ambient	$R_{\theta JA}$	110		

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1	1.73	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =20A	-	17	21	mΩ
		V _{GS} =4.5V,I _D =12A	-	20	24	
Zero Gate Voltage Drain Current	I_{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Q_g	V _{DS} =30V, I _D =15A, V _{GS} =10V ^(Note 1,2)	-	28	-	nC
Gate-Source Charge	Q_gs		-	3.5	-	
Gate-Drain Charge	Q_{gd}		-	6.5	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V,	-	1680	-	pF
Output Capacitance	Coss		-	115	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	85	-	
Turn-On Delay Time	td _(on)	V_{DD} =30V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 1,2)	-	7.2	-	ns
Turn-On Rise Time	t _r		-	38	-	
Turn-Off Delay Time	td _(off)		-	34	-	
Turn-Off Fall Time	t _f		-	8.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı				35	Α
Diode Forward Current	I _S		-	_	აა	Α
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.67	1.0	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =29A, V_{DD} =25V, V_{GS} =10V, R_{G} =25ohm, Starting T_{J} =25 $^{\circ}$ C
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

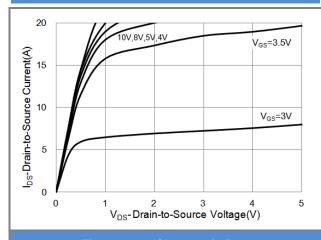


Fig.1 Output Characteristics

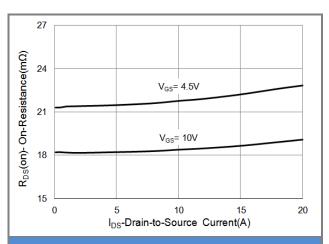


Fig.3 On-Resistance vs. Drain Current

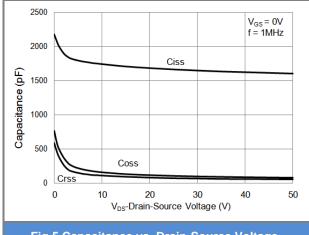


Fig.5 Capacitance vs. Drain-Source Voltage.

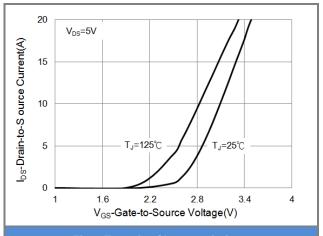


Fig.2 Transfer Characteristics

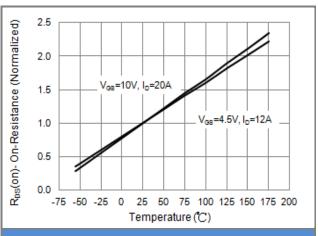


Fig.4 On-Resistance vs. Junction temperature

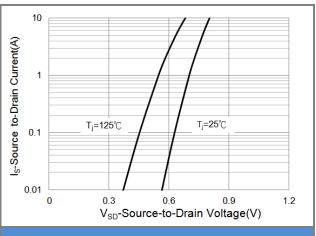


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

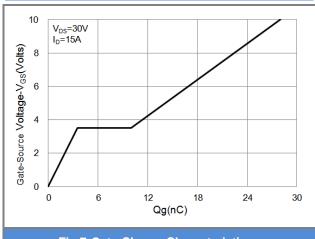
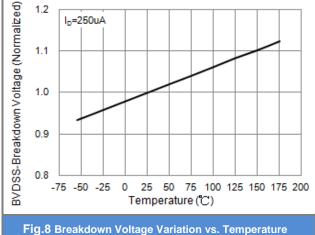


Fig.7 Gate-Charge Characteristics



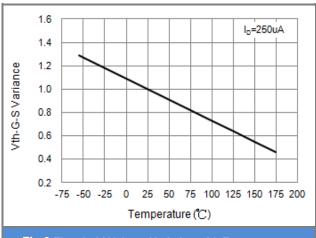


Fig.9 Threshold Voltage Variation with Temperature

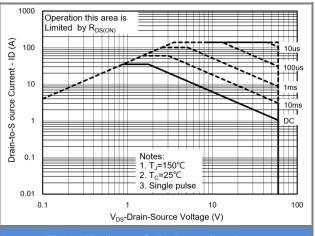
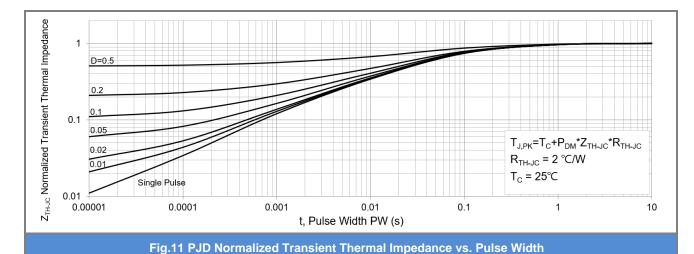


Fig.10 Maximum Safe Operating Area



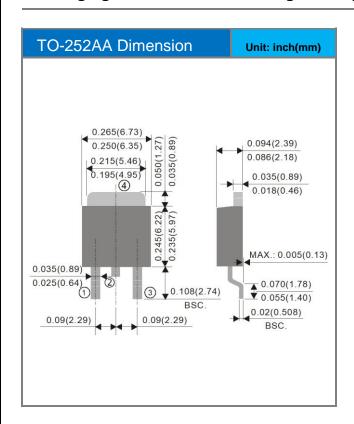


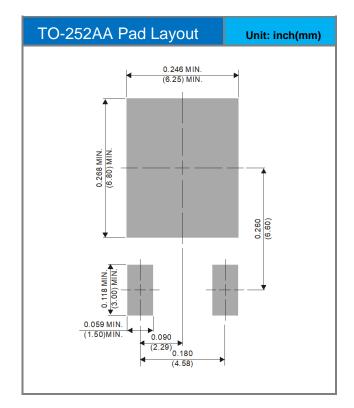


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJD35N06A-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D35N06A	Halogen free	

Packaging Information & Mounting Pad Layout









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